## NSN 5961-01-367-1964

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View Online at https://aerobasegroup.com/nsn/5961-01-367-1964 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 collector to emitter voltage/static/base open and 40.0 collector to emitter voltage, dc with base short-circuited to emitter and 40.0 collector to base voltage/static/emitter open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 500.00 milliamperes emitter current, dc blank and 200.00 milliamperes base current, dc blank **Power Rating Per Characteristic:** 1.2 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 80063-a3005495 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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